

### Features

- High Power
- Fast Speed
- Voltage Ratings to 1500 Volts
- Wide Selection of Carrier Lifetimes
- Wide Selection of Capacitances
- Assortment of Packages Styles
- Available Screened for Military Applications

## **Description and Applications**

M/A-COM's broad line of packaged PIN diodes encompasses a comprehensive range of electrical characteristics and package outlines. This diverse union of semiconductor technology and chip packaging gives considerable flexibility to the circuit designer. The fast switching series of packaged PIN diodes utilize a thin I-region and silicon oxide or glass passivated chips which provide for low leakage currents and low insertion loss. Using in process control monitors to regulate wafer fabrication parameters these devices achieve consistent performance in control circuit applications. The high voltage product line of packaged PIN diodes employs M/A-COM's unique CERMACHIP® passivation process which provides for a hard glass encapsulation that hermetically seals the active area of the chip. These packaged CERMACHIP<sup>®</sup> PIN diodes are ideally suited for use in high power applications where high RF voltages are present. The diode chips are bonded into sealed ceramic packages that are designed for the most stringent electrical and environmental conditions. A wide choice of packages are available which can be mounted into a variety of microwave and RF circuit media. The Packaged PIN Diodes series are designed to have a high inherent reliability and may be ordered screened to meet many MIL-STD reliability levels.

	•
Parameter	Absolution Max.
Voltage	As Specified in Table
Operating Temperature	- 65°C to +175°C
Storage Temperature	- 65°C to +200°C
Operating and Storage (Case Style 1088)	- 65°C to +125°C

## Absolute Maximum Ratings<sup>1</sup>

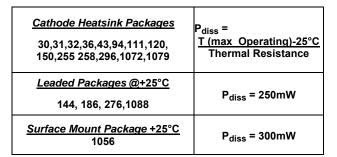
1. Operation beyond any one of the above conditions may cause permanent damage to the device.

Specifications subject to change without prior notification.

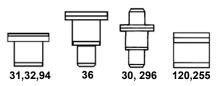
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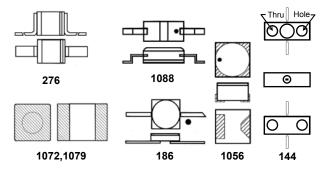
## **Maximum Power Dissipation**



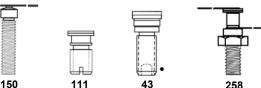
### **Co-Axial Packages**



### Leaded/Surface Mount Packages



### **Threaded Packages**



### **Unpackaged Die**



131,132.134 , 212

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Rev V.9

## 35V to 250V Fast Switching PIN Diodes Specifications ( $T_{AMB} = +25^{\circ}C$ )

	Minimum Reverse	( Unless otherwise specified ) Maximum	( Unless otherwise specified ) Maximum	Maximum Thermal	Nomina	I Characteristics	
Part Number	Voltage <sup>1</sup>	Capacitance	Series Res.	Resistance			I-Region
	@ I <sub>R</sub> <10µA	C⊤@ -10V f = 1MHz	R <sub>s</sub> @ 10mA f = 500MHz		Carrier Lifetime⁴	T <sub>RR</sub> ⁵	Width Microns
	Volts	pF	Ω	°C/W	nS	nS	μM
MA4P202-120	100	0.25	2.50	60	60	5	12
MA4P203-30	100	0.35	1.50	30	100	20	12
MA4P303-32	200	0.35	1.50	30	200	60	20
MA4P404-30	250	0.40²	0.60 <sup>3</sup>	20	1000	100	30

#### Notes:

1. The minimum specified  $V_R$  (Reverse Voltage) is sourced and the resultant reverse leakage current, Ir, is measured to be <10 $\mu$ A

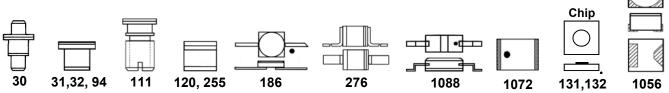
2. At V<sub>R</sub> = -50V

3.  $R_s$  measured at  $I_F$  = +50mA, f = 100MHz.

4. Nominal carrier life time specified with diode biased at  $I_F = +10mA$ ,  $I_{REV} = -6mA$ 

5. Nominal T<sub>RR</sub> (reverse recovery time) specified with diode biased at  $I_F = +20mA$ ,  $I_{REV} = -200mA$ .

### Package Options



Package dimensions can be found on the M/A-COM website at <a href="http://www.macom.com/TechApps/OutlineDrawings.asp">http://www.macom.com/TechApps/OutlineDrawings.asp</a>

## 35V to 500V MELF General Purpose Switching Diodes Specifications (T<sub>AMB</sub> = +25°C)

1	Minimum Reverse Voltage <sup>2</sup>	Maximum Capacitance	(Unless otherwise specified) Maximum Series Res.	CW Power Dissipation Rating	Nominal Characteristics		istics
Part Number <sup>1</sup>	I <sub>R</sub> <10µA Volts	C <sub>T</sub> @10V f = 1MHz pF	R <sub>s</sub> @10mA f = 100MHz Ω	Watts	Typical I <sub>F</sub> When R <sub>S</sub> = 75Ω mA	Carrier Lifetime <sup>3</sup> µS	I-Region Width mils
MA4PH235-1072T	35	1.2	0.5	1.0	_	0.3	0.4
MA4PH236-1072T	200	0.5	3.0	1.0	_	1.5	2.0
MA4PH237-1079T	200	1.5	0.6@50mA	2.0	_	3.0	3.0
MA4PH238-1072T	200	0.5	6.0	1.0	0.30-0.60	2.0	4.0
MA4PH239-1079T	200	0.8	25.0	2.0	1.20-2.40	6.0	14.0
MADP-000234-10720T	500	1.5⁴	0.25@100mA	5.0		3.0	2.0

#### Notes:

- 1. Only available in case styles indicated.
- 2. The minimum specified  $V_R$  (Reverse Voltage) is sourced and the resultant reverse leakage current, Ir, is measured to be <10 $\mu$ A.
- 3. Nominal carrier life time specified with diode biased at  $I_F$  = +10mA ,  $I_{REV}$  = -6mA
- 4. Ct tested at 100V

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Case Styles 1072, 1079



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# Packaged PIN Diodes RoHS Compliant

	Minimum Reverse Voltage <sup>1</sup>	Maximum Capacitance	Maximum Series Resistance	CW Power Dissipation Rating	Nominal Cha	aracteristics
Part Number	I <sub>R</sub> <10μΑ Volts	С⊤@100V f = 1 MHz pF	R <sub>s</sub> @100mA f = 100 MHz Ω	Watts	Carrier Lifetime <sup>2</sup> μS	I-Region Width mils
MA4P504-30	500	0.40	0.60	10	1.0	2
MADP000015-000030 <sup>3</sup>	500	0.55	0.45	15	2.0	2
MA4P506-30	500	0.90	0.30	15	3.0	2

# 500V PIN Diodes Specifications (T<sub>AMB</sub> = +25°C)

#### Notes:

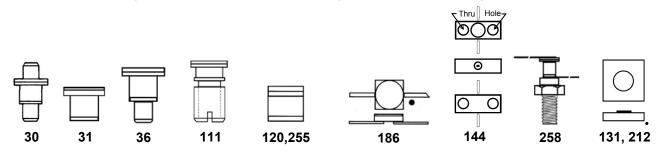
1. The minimum specified V<sub>R</sub> (Reverse Voltage ) is sourced and the resultant reverse leakage current, Ir, is measured to be <10µA.

2. Nominal carrier life time specified with diode biased at  $I_F$  = +10mA ,  $I_{REV}$  = -6mA

3. To order this part in a package other than 30, use the prefix MA4P505 followed by a dash and the desired package style.

### Package Options

Consult the Package Availability Table in the "Ordering Information" section (pg. 7) for part number choices.



Package dimensions can be found on the M/A-COM website at http://www.macomtech.com/TechApps/OutlineDrawings.asp

## 500V MELF PIN Diode Specifications (T<sub>AMB</sub> = +25°C)

	Minimum Reverse Voltage <sup>1</sup>	Maximum Capacitance	Maximum Series Resistance	CW Power Dissipation Rating	Nominal Cha	aracteristics
Part Number	I <sub>R</sub> <10µA Volts	С <sub>т</sub> @100V f = 1 MHz pF	R <sub>s</sub> @100mA f = 100 MHz Ω	Watts	Carrier Lifetime <sup>2</sup> μS	I-Region Width mils
MA4P504-1072T	500	0.5	0.60	10	1.0	2
MA4P505-1072T	500	0.65	0.45	15	2.0	2
MA4P506-1072T	500	1.0	0.30	15	3.0	2

#### Notes:

1. The minimum specified  $V_R$  (Reverse Voltage) is sourced and the resultant reverse leakage current, Ir, is measured to be <10 $\mu$ A.

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#### 1072 Package



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<sup>2.</sup> Nominal carrier life time specified with diode biased at  $I_F$  = +10mA ,  $I_{REV}$  = -6mA



1000V CERMACHIP PIN Diodes Specification (T<sub>AMB</sub> = +25°C) Maximum Minimum **CW** Power Series Reverse Maximum Dissipation **Nominal Characteristics** Voltage<sup>1</sup> Resistance Capacitance Rating Part Number Carrier **I-Region** R<sub>s</sub>@100mA C<sub>T</sub>@100V Lifetime<sup>2</sup> Width f = 100MHz I<sub>R</sub> <10μA f = 1MHz Mils μS Volts pF Ω Watts MA4P604-30 0.50 1000 1.00 15 3.0 4 MA4P606-30 1000 0.80 0.70 20 4.0 4 MA4P607-43 1000 2.00 0.40 25 5.0 4

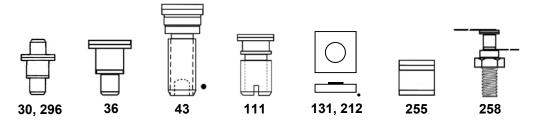
#### Notes:

1. The maximum specified  $V_R$  (reverse voltage) is sourced and the resultant reverse leakage current, Ir, is measured to be <10 $\mu$ A

2. Nominal carrier life time specified with diode biased at  $I_F$  = +10mA ,  $I_{REV}$  = -6mA

### Package Options

### Consult table in "Ordering Information" section (pg. 7) for availability



Package dimensions can be found on the M/A-COM website at http://www.macomtech.com/TechApps/OutlineDrawings.asp

### **1500V CERMACHIP PIN Diode Specifications (T<sub>AMB</sub> = +25°C)**

	Minimum Reverse Voltage <sup>1</sup>	Maximum Capacitance	Maximum Series Resistance	Maximum Thermal Resistance	Nominal Cha	aracteristics
Part Number	I <sub>R</sub> <10µA Volts	Ct @100V f = 1MHz pF	R <sub>s</sub> @200mA f = 100MHz Ω	°C/W	Carrier Lifetime² μS	I-Region Width mils
MA4P709-150	1500	3.30	0.25	2	10.0	7

#### Notes:

1. The minimum specified  $V_R$  (reverse voltage) is sourced and the resultant reverse leakage current, Ir, is measured to be <10 $\mu$ A

2. Nominal carrier life time specified with diode biased at  $I_F$  = +10mA ,  $I_{REV}$  = -6mA



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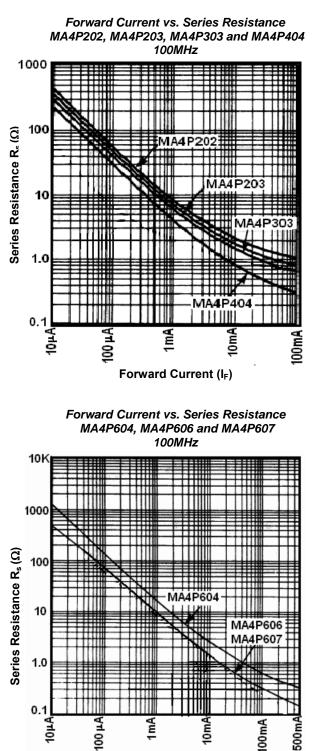
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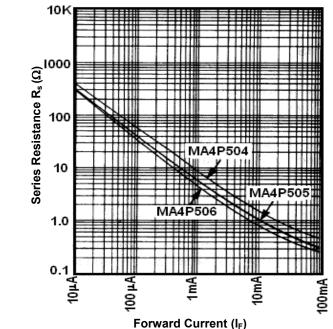


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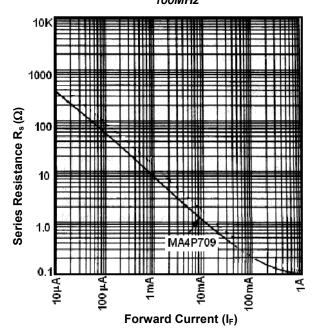
# Packaged PIN Diodes RoHS Compliant



Forward Current vs. Series Resistance MA4P504, MA4P505 and MA4P506 100MHz



#### Forward Current vs. Series Resistance MA4P709 100MHz



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Forward Current (I<sub>F</sub>)



Rev V.9

# Recommended Groups B&C Testing Per MIL-STD 750

Recommended methods and conditions for Groups B and C, TX and TXV level screening.

Inspection	Method	Condition
Storage Temperature	1031	See Maximum Ratings
Operating Temperature		See Maximum Ratings
Temperature Cycling	1051	5 cycles - 65°C to +150°C
Shock	2016	500g's
Vibration	2056	15g's
Constant Acceleration	2006	20,000g's
Humidity	1021	10 Days

# Recommended Screening Per MIL-STD 750

Recommended methods and conditions for TX and TXV level screening.

Inspection	Method	Condition
Internal Visual and / or X-Ray	2072, 2076	See Note
High Temp. Storage	1032	48 hours min. @ max. storage temp.
Thermal Shock	1051	10 Cycles
Constant Acceleration	2006	20,000 g's, Y1
Fine Leak	1071	Н
Gross Leak	1071	C or E
Electrical		See Note
Burn-In	1038	See Note

#### Notes:

1. Conditions and details of test depend on specific model number. Information available upon request.

2. Case styles 1056 and 1088 are not military, MIL-STD-750, rated packages.

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### **Maximum Soldering Temperature**

#### For hand soldering operation:

#### Case Style: 144,150\*,186, 258\*, 1088, 1072, 1079 ◆ 265°C maximum for 5 seconds Case Style: 120, 255, 276 ◆ 265°C maximum for 5 seconds. Case Style: 30\*, 31, 32, 36\*, 43\*, 94, 111\*, 296\* ◆ 225°C maximum for 5 seconds. \*Note:

Package styles that are threaded or have pronged ends rely on a pressure connection and do not require solder attachment but can be soldered if desired.

#### For solder reflow profiles:

Refer to application note M-538 on the M/A-COM website using the following link: http://www.macomtech.com/Application%20Notes/pdf/M538.pdf

### **Ordering Information**

The Packaged PIN Diode specifications shown in the tables on pages 2, 3, & 4 are for the standard style package. The standard package style is indicated by the number following the dash after the base part number. Note that the specification tables lists the total diode capacitance for the standard case style. The total capacitance for the base part in an alternative package will differ and is computed by adding the junction capacitance of the chip and the parasitic capacitance of the alternative package as defined in the **Package Parasitic Capacitance** table below. To compute the chip junction capacitance, subtract the total capacitance shown in the specifications tables on pages 2, 3, & 4 from the appropriate standard style package capacitance below. To order, indicate the base part number followed by a dash and the desired package style.

For example: The MA4P506-258 is the MA4P506 chip in the 258 style package.

r donago / tranability rabio						
Base Part Number	Available ODS Package Styles					
MA4P202	120, 134, 276, 1056					
MA4P203	30, 32, 94, 111, 134, 1056					
MA4P303	32, 36, 94, 120, 186, 255, 1088					
MA4P404	30, 31, 36, 111, 132, 258,1072T*					
MA4P504	30, 120, 132, 144, 186, 255,1072T*					
MA4P505	36, 131, 255, 1072T*					
MA4P506	30, 31, 36, 131, 255, 258, 1072T*					
MA4P604	30, 43, 131, 255, 258					
MA4P606	30, 36, 131, 258					
MA4P607	43, 212, 296					
MA4P709	150					
MADP000015-000030	30					
MA4PH235	1072T*					
MA4PH236	1072T*					
MA4PH237	1079T*					
MA4PH238	1072T*					
MA4PH239	1079T*					
MADP-000234	10720T* (1072 package style)					

### Package Availability Table

(pF) 8 8
8
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0
8
'5
5
27
3
chip)
chip)
chip)
2
5
chip)
0
8
3
5
20
6
3
2

Package Parasitic Capacitance

\*Note: "T" after the package style number indicates tape and reel.

Tape and reel information can be found on the M/A-COM website at <a href="http://www.macomtech.com/Application%20Notes/pdf/M513.pdf">http://www.macomtech.com/Application%20Notes/pdf/M513.pdf</a>

Package dimensions can be found on the M/A-COM website at http://www.macomtech.com/TechApps/OutlineDrawings.asp

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